捷多邦,专业PCB打样工厂,24小时加食**A79**00 SERIES NEGATIVE-VOLTAGE REGULATORS

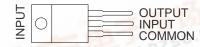
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- 3-Terminal Regulators
- Output Current Up To 1.5 A
- No External Components
- Internal Thermal Overload Protection
- High-Power Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation

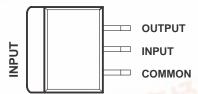
description/ordering information

This series of fixed-negative-voltage integrated-circuit voltage regulators is designed to complement Series µA7800 in a wide range of applications. These applications include on-card regulation for elimination of noise and distribution

KCS (TO-220) PACKAGE (TOP VIEW)







problems associated with single-point regulation. Each of these regulators can deliver up to 1.5 A of output current. The internal current limiting and thermal shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

ORDERING INFORMATION

TJ	V _{O(NOM)}	PACKAGET		ORDERABLE PART NUMBER	TOP-SIDE MARKING
W.	-15	Power Flex (KTE)	Reel of 2000	μΑ7915CKTER	μA7915C
	-15	TO-220, short shoulder (KCS)	Tube of 50	μA7915CKCS	μA7915C
	40	Power Flex (KTE)	Reel of 2000	μA7912CKTER	μA7912C
0°C to 125°C	-12	TO-220, short shoulder (KCS)	Tube of 50	μA7912CKCS	μA7912C
0.0 10 125.0	_	Power Flex (KTE)	Reel of 2000	μA7908CKTER	μA7908C
	-8	TO-220, short shoulder (KCS)	Tube of 50	μA7908CKCS	μA7908C
		Power Flex (KTE)	Reel of 2000	μΑ7905CKTER	μA7905C
	-5	TO-220, short shoulder (KCS)	Tube of 50	μA7905CKCS	μA7905C

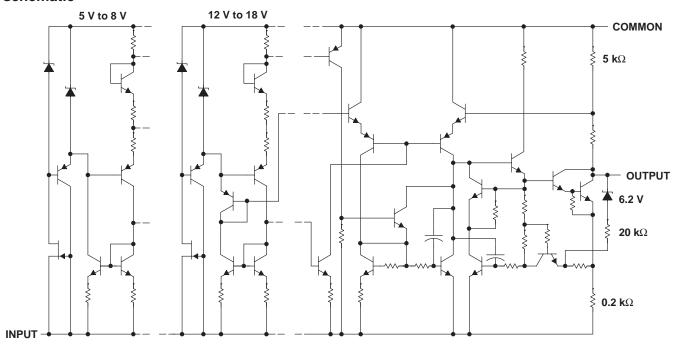
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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schematic



All component values are nominal.

absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V _I : µA/924C	
All others	
Operating virtual junction temperature, T _J	150°C
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

package thermal data (see Note 1)

PACKAGE	BOARD	θЈС	θ JA
Power Flex (KTE)	High K, JESD 51-5	3°C/W	23°C/W
TO-220 (KCS)	High K, JESD 51-5	3°C/W	19°C/W

NOTE 1: Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

recommended operating conditions

			MIN	MAX	UNIT
	μΑ7905	С	-7	-25	
. v.	μΑ7908	С	-10.5	-25	V
٧ı	Input voltage µA7912	С	-14.5	-30	V
	μΑ7915	С	-17.5	-30	
lo	IO Output current			1.5	Α
TJ	Operating virtual junction temperature		0	125	°C



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electrical characteristics at specified virtual junction temperature, $V_I = -10 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETED	TEST COMPITIONS	- +	μ Α7905C			UNITS
PARAMETER	TEST CONDITIONS	T _J †	MIN	TYP	MAX	UNITS
		25°C	-4.8	-5	-5.2	
Output voltage‡	$I_O = 5 \text{ mA to 1 A},$ P \le 15 W $V_I = -7 \text{ V to } -20 \text{ N}$	/, 0°C to 125°C	-4.75		-5.25	V
lanut regulation	$V_{ } = -7 \text{ V to } -25 \text{ V}$			12.5	50	mV
Input regulation	V _I = -8 V to -12 V			4	15	IIIV
Ripple rejection	$V_I = -8 \text{ V to } -18 \text{ V}, \qquad f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Output regulation	I _O = 5 mA to 1.5 A			15	100	mV
Output regulation	I _O = 250 mA to 750 mA			5	50	IIIV
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.4		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		125		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		1.5	2	mA
Dies surrent shangs	V _I = -7 V to -25 V			0.15	0.5	A
Bias current change	I _O = 5 mA to 1 A			0.08	0.5	mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, V_I = -11 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ Α7906C			UNITS	
PARAMETER	TEST CONDITIONS	T _J †	MIN	TYP	MAX	UNITS	
		25°C	-5.75	-6	-6.25		
Output voltage [‡]	$I_O = 5$ mA to 1 A, $V_I = -8$ V to -21 V, $P \le 15$ W	0°C to 125°C	-5.7		-6.3	V	
lanut regulation	$V_{I} = -8 \text{ V to } -25 \text{ V}$			12.5	120	mV	
Input regulation	V _I = -9 V to -13 V			4	60	mv	
Ripple rejection	$V_I = -9 \text{ V to } -19 \text{ V}, \qquad f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB	
Outrot as mulation	I _O = 5 mA to 1.5 A	/		15	120) \	
Output regulation	I _O = 250 mA to 750 mA	1		5	60	mV	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.4		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		150		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		1.5	2	mA	
Diag surrent shares	$V_{I} = -8 \text{ V to } -25 \text{ V}$			0.15	1.3	A	
Bias current change	I _O = 5 mA to 1 A	1		0.08	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = -14 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	t	μ Α7908C			UNITS	
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS	
		25°C	-7.7	-8	-8.3		
Output voltage‡	I_{O} = 5 mA to 1 A, V_{I} = -10.5 V to -23 V, $P \le$ 15 W	0°C to 125°C	-7.6		-8.4	V	
lanut regulation	$V_{I} = -10.5 \text{ V to } -25 \text{ V}$			12.5	160	mV	
Input regulation	V _I = −11 V to −17 V			4	80	IIIV	
Ripple rejection	V _I = -11.5 V to -21.5 V, f = 120 Hz	0°C to 125°C	54	60		dB	
0	I _O = 5 mA to 1.5 A			15	160	mV	
Output regulation	I _O = 250 mA to 750 mA			5	80	IIIV	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.6		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		200		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		1.5	2	mA	
Diag surrent shares	V _I = -10.5 V to -25 V			0.15	1	Λ	
Bias current change	I _O = 5 mA to 1 A]		0.08	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -19~V$, $I_O = 500~mA$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ Α7912C			UNITS	
PARAMETER	TEST CONDITIONS	T _J †	MIN	TYP	MAX	UNITS	
		25°C	-11.5	-12	-12.5		
Output voltage [‡]	I_{O} = 5 mA to 1 A, V_{I} = -14.5 V to -27 V, $P \le$ 15 W	0°C to 125°C	-11.4		-12.6	V	
Input regulation	V _I = -14.5 V to -30 V			5	80	mV	
Input regulation	V _I = -16 V to -22 V	1		3	30	mv	
Ripple rejection	$V_I = -15 \text{ V to } -25 \text{ V}, f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB	
Output no mulation	I _O = 5 mA to 1.5 A			15	200	\/	
Output regulation	I _O = 250 mA to 750 mA	1		5	75	mV	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.8		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		300		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		2	3	mA	
Diag assessed about a	V _I = -14.5 V to -30 V			0.04	0.5	A	
Bias current change	I _O = 5 mA to 1 A	1		0.06	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = -23 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETER	TEST COMPITIONS	- +	μ Α7915C			UNITS	
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNIIS	
		25°C	-14.4	-15	-15.6		
Output voltage‡	I_O = 5 mA to 1 A, V_I = -17.5 V to -30 V, $P \le 15$ W	0°C to 125°C	-14.25		-15.75	V	
lanut regulation	$V_{I} = -17.5 \text{ V to } -30 \text{ V}$			5	100	mV	
Input regulation	$V_{I} = -20 \text{ V to } -26 \text{ V}$	1		3	50	IIIV	
Ripple rejection	$V_I = -18.5 \text{ V to } -28.5 \text{ V}, f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB	
Output regulation	I _O = 5 mA to 1.5 A			20	300	mV	
Output regulation	I _O = 250 mA to 750 mA	1		8	150	mv	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-1		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		375		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		2	3	mA	
Dies surrent shangs	V _I = −17.5 V to −30 V			0.04	0.5	A	
Bias current change	I _O = 5 mA to 1 A	1		0.06	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-µF capacitor across the input and a 1-µF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -27~V,\,I_O = 500~mA$ (unless otherwise noted)

DADAMETER	TEST CONDITIONS	T.+	μ Α7918C			UNITS	
PARAMETER	TEST CONDITIONS	T _J †	MIN	TYP	MAX	UNITS	
		25°C	-17.3	-18	-18.7		
Output voltage [‡]	I_{O} = 5 mA to 1 A, V_{I} = -21 V to -33 V, $P \le 15$ W	0°C to 125°C	-17.1		-18.9	V	
lanut regulation	V _I = −21 V to −33 V			5	360	mV	
Input regulation	$V_{I} = -24 \text{ V to } -30 \text{ V}$			3	180	IIIV	
Ripple rejection	V _I = -22 V to -32 V, f = 120 Hz	0°C to 125°C	54	60		dB	
Output no mulation	I _O = 5 mA to 1.5 A			30	360	360	
Output regulation	I _O = 250 mA to 750 mA	1		10	180	mV	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-1		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		450		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		2	3	mA	
Diag surrent shares	V _I = -21 V to -33 V			0.04	1	Λ	
Bias current change	I _O = 5 mA to 1 A	1		0.06	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = -33 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

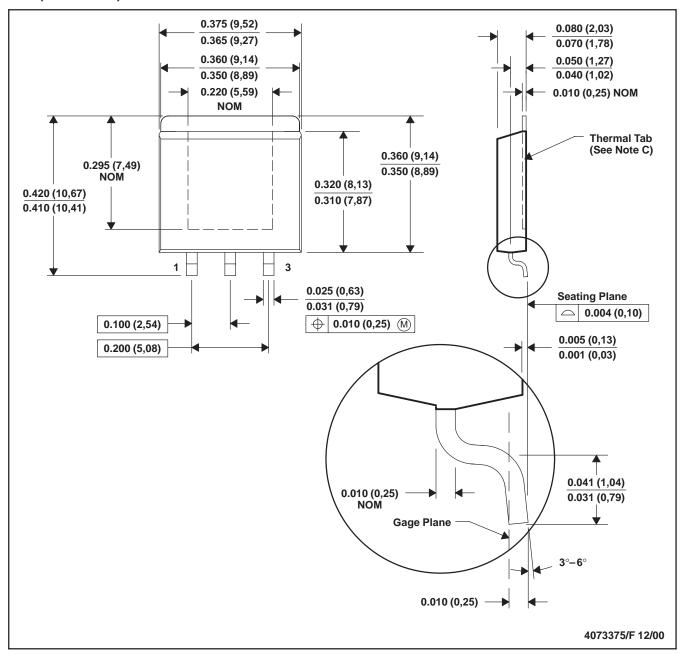
DADAMETED	TEST CONDITIONS	- +	μ Α7924C			UNITS	
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS	
		25°C	-23	-24	-25		
Output voltage‡	I_O = 5 mA to 1 A, V_I = -27 V to -38 V, $P \le$ 15 W	0°C to 125°C	-22.8		-25.2	V	
lanut regulation	$V_{I} = -27 \text{ V to } -38 \text{ V}$			5	480	\/	
Input regulation	$V_{I} = -30 \text{ V to } -36 \text{ V}$			3	240	mV	
Ripple rejection	$V_I = -28 \text{ V to } -38 \text{ V}, \text{ f} = 120 \text{ Hz}$	0°C to 125°C	54	60		dB	
Outrat as sulption	I _O = 5 mA to 1.5 A			85	480	\/	
Output regulation	I _O = 250 mA to 750 mA	1		25	240	mV	
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-1		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz	25°C		600		μV	
Dropout voltage	I _O = 1 A	25°C		1.1		V	
Bias current		25°C		2	3	mA	
Bias current change	V _I = −27 V to −38 V			0.04	1	A	
	I _O = 5 mA to 1 A	1		0.06	0.5	mA	
Peak output current		25°C		2.1		Α	

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



KTE (R-PSFM-G3)

PowerFLEX™ PLASTIC FLANGE-MOUNT



NOTES: A. All linear dimensions are in inches (millimeters).

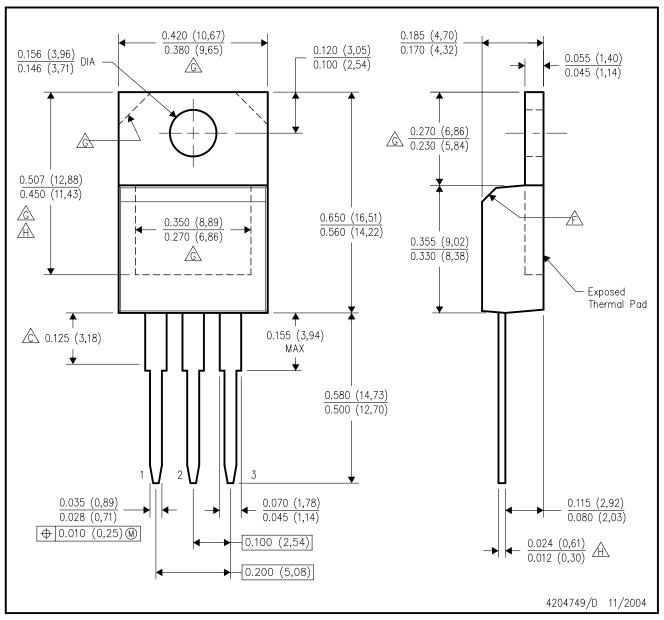
- B. This drawing is subject to change without notice.
- C. The center lead is in electrical contact with the thermal tab.
- D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
- E. Falls within JEDEC MO-169

PowerFLEX is a trademark of Texas Instruments.



KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



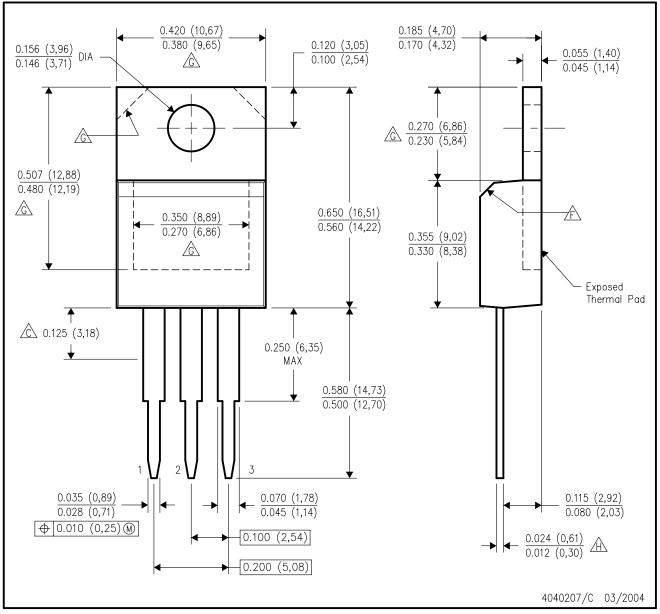
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- Falls within JEDEC TO—220 variation AB, except minimum lead thickness and minimum exposed pad length.



KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- Falls within JEDEC TO-220 variation AB, except minimum lead thickness.



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